

MJE200

Feature

- Low Collector-Emitter Saturation Voltage
- High Current Gain Bandwidth Product : f_T =65MHz @ I_C =100mA (Min.)
- Complement to MJE210



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	40	V
V _{CEO}	Collector-Emitter Voltage	25	V
V _{EBO}	Emitter- Base Voltage	8	V
I _C	Collector Current	5	Α
P _C	Collector Dissipation (T _C =25°C)	15	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

Electrical Characteristics $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	25		V
I _{CBO}	Collector Cut-off Current	V _{CB} =40V, I _E =0		100	nA
		V _{CB} =40V, I _E =0 @ T _J =125°C		100	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{BE}=8V, I_{C}=0$		100	nA
h _{FE}	DC Current Gain	V _{CE} =1V, I _C =500mA	70		
		V _{CE} =1V, I _C =2A	45	180	
		V_{CE} =2V, I_{C} =5A	10		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =500mA, I _B =50mA		0.3	V
		I _C =2A, I _C =200mA		0.75	V
		I _C =5A, I _B =1A		1.8	V
V _{BE} (sat)	Base- Emitter Saturation Voltage	I _C =5A, I _B =1A		2.5	V
V _{BE} (on)	Base-Emitter ON Voltage	V _{CE} =1V, I _C =2A		1.6	V
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =100mA	65		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=0.1MHz		80	pF

Typical Characteristics

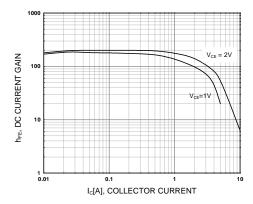


Figure 1. DC current Gain

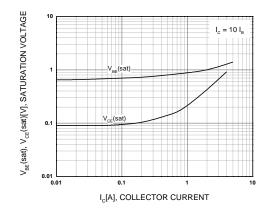


Figure 2. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

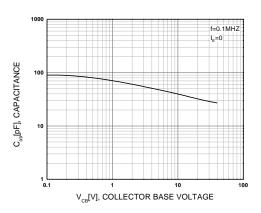


Figure 3. Collector Output Capacitance

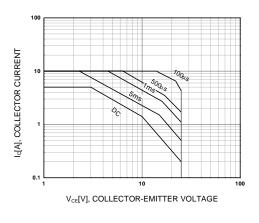


Figure 4. Safe Operating Area

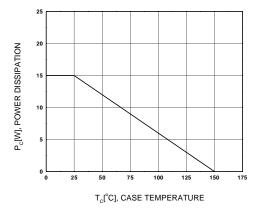
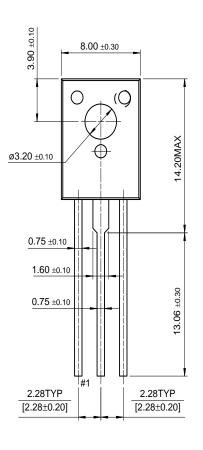


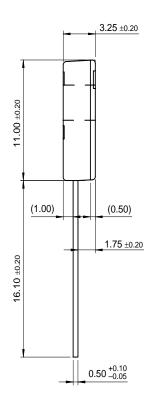
Figure 5. Power Derating

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Package Demensions

TO-126





Dimensions in Millimeters

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